



Article Computer Simulation of Phase Transitions in Thin Films with an Antidote Lattice

Sergey V. Belim^{1,*}, Sofya S. Belim¹, Ilya V. Tikhomirov¹ and Igor V. Bychkov²

- ¹ Department of Physics, Omsk State Technical University, 644050 Omsk, Russia
- ² Department of Radiophysics and Electronics, Chelyabinsk State University, 454001 Chelyabinsk, Russia

* Correspondence: sbelim@mail.ru or svbelim@omgtu.ru

Abstract: We investigate the magnetic phase transition in a thin film with an antidote lattice by computer simulation. A lattice of non-magnetic antidotes is present in a thin film of several atomic layers. The antidotes form a rectangular lattice. We are looking at two forms of antidotes. The Ising model and Wolf' cluster algorithm simulate the system's magnetic behavior. Antidotes act on additional surfaces of the system. This results in a change in the Curie temperature of the system. Dependence of phase transition temperature on holes size and shape is obtained. The phase transition temperature depends on the size of the hole by logarithmic law. The Curie temperature for triangular holes is lower than for square holes. We investigated the magnetization of a thin film with an antidote lattice and constructed a hysteresis loop. The hysteresis loop expands as the hole size decreases. Coercive force depends on the size and shape of the holes. Coercive force varies by nonlinear law.

Keywords: antidots lattice; computer simulation; phase transition; thin film



Citation: Belim, S.V.; Belim, S.S.; Tikhomirov, I.V.; Bychkov, I.V. Computer Simulation of Phase Transitions in Thin Films with an Antidote Lattice. *Coatings* **2022**, *12*, 1526. https://doi.org/10.3390/ coatings12101526

Academic Editors: Ştefan Ţălu and Emerson Coy

Received: 3 September 2022 Accepted: 11 October 2022 Published: 12 October 2022

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1. Introduction

Ferromagnetic antidote structures are continuous films with a periodic lattice of holes [1,2]. This peculiarity changes the magnetic properties of materials. Thin film materials with controlled parameters are important in the creation of spintronic devices. Magnetic films with antidotes are promising materials for the creation of new generation magnetic transistors [3–5]. Magnetic recording media are created on their basis [6]. Antidotes increase the inner surface of materials. The result of the surface increase is a variation in the optical [7,8], electrical [9,10] and magnetic [11] properties of the film. Several approaches for producing film with antidotes currently exist: electron beam lithography [12,13], focal ion milling [14] and self-assembly of nanoscale spheres [7,15,16]. These methods control the size of antidotes, their relative position and the distance between them.

A lattice of non-magnetic holes creates a demagnetization field. This field affects the movement of the magnetic domain walls. Walls of magnetic domains are fixed on antidotes, leading to an increase in coercive force [17–20]. Antidote lattice affects magnetic resistance, magnetic permeability and magnetic anisotropy of the film [11,21–27]. The presence of holes slows down the magnetic relaxation process [28–31]. The presence of triangular antidotes increases the relaxation time by nine times compared to relaxation of continuous film. Magnetic domains are bound be the edges of the antidotes. Magnetization takes longer to reverse. Micromagnetic simulations in combination with X-ray microscopy showed that for small antidote sizes, the dominant contribution yields an exchange interaction [32].

Experimental methods investigate thin films with antidotes lattice based on different materials. Experimental studies for the spin dynamics in NiFe thin film with an antidote lattice on a silicone substrate demonstrated the dependence of the magnetic properties in the system on the size and mutual location of holes [33]. Fe, Co and Permalloy (Py) films with antidotes are created using nanospheric lithography [34]. Studies of magnetization of these films demonstrate an increase in hysteresis loop width with an increase in the linear dimensions of antidotes and the distance between them. Coercive force grows by

linear law. Changing the size of the holes and the distance between them in the Co film creates a coercive force with a given value [35]. Hole sizes vary from 20 nm to 60 nm. The hysteresis loop changes shape as the hole sizes and the distances between them increase. The dependence of coercive force on the external magnetic field is close to linear. The square antidotes lattice in thin films Fe, Ni and NiFe makes it possible to investigate the dependence of coercive force on its parameters and film material [36]. Coercive force changes by nonlinear law as the linear dimensions of the holes in these experiments increase. Studies of the antidote lattice in the Co film using electron scanning spectroscopy revealed a dependence of magnetic properties on the lattice's symmetry [25,37]. The properties of the film depend on the shape, mutual location and dimensions of the holes, as well as the distance between them.

The purpose of this article is to simulate phase transitions in thin films with an antidote array.

2. Model

We consider a two-dimensional film with a thickness of D atomic layer. The antidote lattice is implemented as square-shaped holes. Holes are located in nodes of the square grid with period d. The side of the hole square equal a. The geometry of the system is shown in Figure 1.





We use the Ising model to study the magnetic properties of the system. Each film atom has a spin S_i . Spin projection can take one of two values (1/2 or -1/2). We consider a simple ferromagnetic material with an exchange interaction. The exchange integral is J. The Hamiltonian is equal to the sum of the pairwise spins' interactions for such system.

$$H = -J\sum S_i S_j + \mu_B h_0 \sum S_i.$$
⁽¹⁾

Spins S_i and S_j in the first term are the spins of nearest neighbors. The second term describes the interaction with the external magnetic field. μ_B is a Bohr magneton, and h_0 is an external magnetic field. The second term contains the calculation of the sum of all the system spins.

It is more convenient to use relative values in computer modeling. The reduced temperature T is used instead of the actual temperature t.

$$T = \frac{k_B t}{J}.$$
 (2)

Similarly, the reduced magnetic field strength h is used in the calculations instead of the actual external magnetic field strength h_0 .

$$h = \frac{\mu_B h_0}{J}.$$
 (3)

The Hamiltonian has been rewritten in given values.

$$H/J = -\sum S_i S_j + h \sum S_i.$$
⁽⁴⁾

We use the sum of spin projections to determine magnetization.

$$m = \sum_{i=1}^{N} S_i / N.$$
(5)

N is the total number of spins in the system. Magnetization is an order parameter at ferromagnetic phase transition.

The system is located between the z = 0 and z = D - 1 planes. Periodic boundary conditions are applied to the system along the OX and OY axes. We use the Wolf's cluster algorithm [38] to model a system near the Curie point.

Fourth-order Binder cumulants [39] make it possible to determine the Curie temperature of the system.

$$U_4 = 1 - \frac{\langle m^4 \rangle}{3\langle m^2 \rangle^2}.\tag{6}$$

Cumulants use a thermodynamic average over different system configurations. Angle brackets mean a thermodynamic averaging operation. The main property of fourth-order Binder cumulants is that their values are independent of the simulated system dimensions at the phase transition point. Systems with different linear size L are simulated. The dependence of U_4 on temperature is constructed for each system. All of these plots intersect at one point. This point corresponds to the Curie temperature T_C for the system.

Critical phenomena are present in the system near the Curie point. These phenomena lead to singular behavior of thermodynamic functions. Power functions approximate the dependence of thermodynamic parameters on temperature. Exponents of such functions are called critical exponents. The critical exponential β describes the behavior of magnetization.

$$m \sim |T - T_c|^{\beta}. \tag{7}$$

The critical exponential γ describes the behavior of magnetic susceptibility.

$$\chi = \frac{\partial m}{\partial h} \sim |T - T_c|^{-\gamma}.$$
(8)

The critical exponential ν describes the growth of the correlation radius r_c .

$$r_c \sim |T - T_c|^{-\nu}.\tag{9}$$

Magnetic susceptibility is calculated based on thermodynamic magnetization averages.

$$\chi = \frac{N}{T} \left(\left\langle m^2 \right\rangle - \left\langle m \right\rangle^2 \right). \tag{10}$$

Finite-dimensional scaling theory [40] expresses these quantities through the size of the system *L*.

$$m \sim L^{\beta/\nu}, \quad \chi \sim L^{-\gamma/\nu}.$$
 (11)

We model systems with different linear size *L* and calculate the ratio of the critical exponents γ/ν and β/ν .

We use the Metropolis algorithm to build a hysteresis loop [41]. Wolf's cluster algorithm significantly speeds up calculations when determining phase transition parameters. But this algorithm erases all information about the previous state of the system. This property does not allow it to be used in the study of system magnetization.

3. Phase Transition

In the first computer experiment, we examine systems with hole sizes equal to half the period of grid (a = d/2). Hole size increases as antidote lattice period increases. The period varies from d = 4 to d = 16 in increments $\Delta d = 2$. The linear dimensions of the system include an integer number of periods. This requirement is a consequence of periodic boundary conditions. We use systems with linear dimensions from L = 2d to L = 6d in increments $\Delta L = d$. The film thickness is four atomic layers (D = 4). A plot of Curie temperature T_C versus lattice period d is shown in Figure 2.



Figure 2. The dependence of the Curie temperature T_C on the antidotes lattice period *d* with the hole size a = d/2. The black line is the result of a computer experiment. A red line approximates a logarithmic function. The blue line is the Curie temperature for a continuous film.

As can be seen from Figure 2, the logarithmic function approximates the Curie temperature versus antidote lattice period at $d \le 12$.

$$T_{\rm C} = 2.384 + 0.347 \cdot \ln d. \tag{12}$$

The phase transition temperature approaches the Curie point for the continuous film ($T_0 = 3.56$) as the period increases. Deviation from logarithmic dependence and transition to asymptotic value T_0 occurs at period of antidote lattice d > 12. This behavior is associated with a change in the inner surface of the film by one spin. The inner surface area S_s for the film is equal to the total number of spins on the surfaces of the individual holes.

$$S_s = \left(\frac{L}{d}\right)^2 \cdot 4D\frac{d}{2} = \frac{2L^2D}{d}.$$
(13)

We calculate the number of spins in a film with holes a = d/2.

$$N = \left(\frac{L}{d}\right)^2 \cdot \left(Dd^2 - D\frac{d^2}{4}\right) = \frac{3}{4}L^2D.$$
(14)

The inner surface per spin is equal to the ratio of these values.

$$\frac{S_s}{N} = \frac{8}{3d}.$$
(15)

The inner surface decreases by one spin as the antidote lattice period increases. The antidote lattice film tends to be a continuous film in its properties.

The dependence of the critical exponents' ratio γ/ν and β/ν on the antidotes lattice period *d* is shown in Figure 3.



Figure 3. Relationship of critical exponents (**a**) γ/ν and (**b**) β/ν to antidote lattice period *d* with hole size a = d/2. A red line is a critical exponent for a continuous film. Points denote critical exponents for different periods of the antidote lattice. A red line is a critical exponent for a solid film.

Critical exponents are independent of the antidote's presence. The ratios of critical exponents for a continuous film with thickness D = 4 are $\gamma/\nu = 1.76$ and $\beta/\nu = 0.10$. Critical exponents for antidote lattice film are $\gamma/\nu = 1.78 \pm 0.03$ and $\beta/\nu = 0.09 \pm 0.01$. These values match with the errors.

We investigated the dependence of the magnetic properties of the system on the distance between the holes and the holes shape in a second computer experiment. Two holes shapes were present in the second experiment. The first lattice contains square holes with constant side a = 4. The second lattice contains triangular holes. The base of the triangle is a = 7. The height of the triangle is 4. Both types of holes exclude 16 spins from the lattice. The hole areas can be considered the same and equal to 16. The shape of the holes is shown in Figure 4.



Figure 4. Hole shapes: (a) square, (b) triangular.

This computer experiment demonstrates the dependence of magnetic properties only on the shape of the holes, but not on their size. The antidote lattice period varied from d = 10 to d = 16 in steps $\Delta d = 2$. Curie temperature T_C versus antidote lattice period d is shown in Figure 5.



Figure 5. The dependence of the Curie temperature T_C on the antidotes lattice period *d* for holes with a constant size: (a) square holes, (b) triangular holes. The red line is the Curie temperature for triangular holes and the black line is the Curie temperature for square holes.

The graphs in Figure 5 show the dependence of Curie temperature on the hole's shape. The triangular antidote lattice has a lower phase transition temperature. The Curie temperature for systems with a constant hole size is rising faster than for systems with increasing holes. This is due to a faster decrease in the area of the inner surface on the spin.

$$\frac{S_s}{N} = \frac{16}{d^2 - 16}.$$
(16)

The logarithmic law does not hold in this case. Critical exponents for these systems also coincide with values for thin film.

4. Hysteresis Loop

We investigate the process of magnetizing thin films with an antidote lattice. The holes have a constant size. The film thickness is D = 4. Square holes have side a = 4. The antidote lattice period varies from d = 6 to d = 24. The linear size of the film is proportional to the whole number of periods for performing periodic boundary conditions. We are investigating systems with linear size L = 8d. The film temperature is T = 2.5. This temperature provides a ferromagnetic phase for films with any antidote lattice period. Magnetic field varies from h = 1 to h = -1 with pitch $\Delta h = 0.01$. An example of hysteresis loops for antidote lattices with different periods is shown in Figure 6.



Figure 6. An example of hysteresis loops for a = 4 and different antidote lattice period d: d = 6 (black line), d = 8 (red line), d = 16 (blue line).

The hysteresis loop width increases as the antidote lattice period increases. This dependence is due to the reduction of the free surface by one spin. The average number of neighbors in one spin decreases as the free surface decreases. This complicates the process of changing the spin direction. Coercive force increases as a result of this. The dependence of coercive force H_C on the antidote lattice period *d* is shown in Figure 7.



Figure 7. Dependence of coercive force H_C on antidote lattice period *d*.

Coercive force grows nonlinearly with increasing antidote lattice period. The coercive force value tends to a limit value for a solid thin film as the period of the antidote lattice grows.

5. Conclusions

We investigated thin films with antidote lattice by computer simulation. The results demonstrate agreement with the experimental data. The magnetic properties of the system depend on the hole's shape and dimensions. The lattice period has a strong effect on Curie temperature. The main factor affecting the magnetic properties of the antidote lattice film is the free surface area. The hole's shape changes the Curie temperature of the system. If the hole's dimension increases in proportion to the antidote lattice period, then the phase transition temperature increases according to the logarithmic law. If the hole's dimension remains constant, the increase in the phase transition temperature is faster. The Curie temperature tends to a value for a continuous film in all cases. Critical exponents are independent of the antidote lattice. Their values coincide with the critical exponents for the continuous film.

The width of the hysteresis loop depends on the antidote lattice period. Coercive force grows by nonlinear law. This results is in good agreement with the experimental data [25,33,34,37,38,42,43] and the results of micromagnetic modeling [35].

Author Contributions: Conceptualization, S.V.B.; funding acquisition, I.V.B.; investigation, S.V.B., I.V.T. and S.S.B.; methodology, I.V.B. and S.V.B.; project administration, I.V.B.; software, I.V.T., S.S.B.; writing—original draft, S.V.B. and S.S.B. All authors have read and agreed to the published version of the manuscript.

Funding: This research was funded by Russian Science Foundation, project No. 22-19-00355.

Institutional Review Board Statement: Not applicable.

Informed Consent Statement: Not applicable.

Data Availability Statement: Not applicable.

Conflicts of Interest: The authors declare no conflict of interest.

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